

# isc N-Channel MOSFET Transistor

# STP9NK90Z

#### **FEATURES**

- Drain Current : I<sub>D</sub>= 8A@ T<sub>C</sub>=25℃
- Drain Source Voltage
  - : V<sub>DSS</sub>= 900V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)} = 1.3 \Omega (Max) @ V_{GS} = 10V$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## **DESCRIPTION**

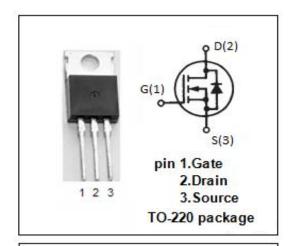
 motor drive, DC-DC converter, power switch and solenoid drive.

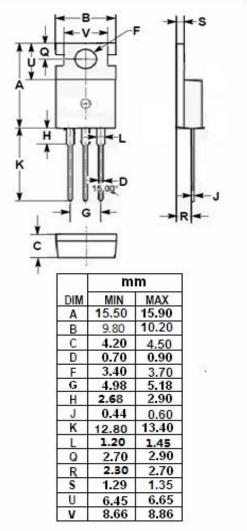
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	900	V
V <sub>GSS</sub>	Gate-Source Voltage	±30	V
I <sub>D</sub>	Drain Current-Continuous;@Tc=25℃	8	А
I <sub>DM</sub>	Drain Current-Single Pulsed	32	А
P <sub>D</sub>	Total Dissipation	160	W
T <sub>j</sub>	Operating Junction Temperature -55~150		$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.78	°C/W







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### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 1mA	900	-	-	V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> = 0.1mA	3	-	4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =3.6A	-	-	1.3	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±20V;V <sub>DS</sub> = 0V	-	-	±10	uA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 900V; V <sub>GS</sub> = 0V	-	-	1	uA
V <sub>SD</sub>	Diode forward voltage	I <sub>SD</sub> = 8A, V <sub>GS</sub> = 0 V	-	-	1.6	V

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